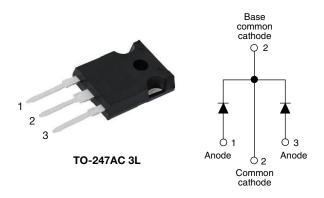
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A

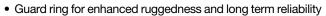


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PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 20 A							
V _R	45 V							
V _F at I _F	0.56 V							
I _{RM} max.	110 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	20 mJ							
Package	TO-247AC 3L							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBR4045WT... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform (per device)	40	٨						
I _{FRM}	$T_{\rm C} = 125 \ ^{\circ}{\rm C}$ (per leg)	40	A						
V _{RRM}		45	V						
I _{FSM}	t _p = 5 μs sine	1020	А						
V _F	20 A _{pk} , T _J = 125 °C	0.56	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBR4045WT-N3	UNITS				
Maximum DC reverse voltage	V _R		М				
Maximum working peak reverse voltage	V _{RWM}	45	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER SYMBOL TEST CONDITIONS				VALUES	UNITS				
Maximum average forward currentper legper device		I	T _C = 125 °C, 50 % duty cycle,	rootangular wavoform	20				
		I _{F(AV)}	$1C = 123^{\circ} C, 30^{\circ} \%$ duty cycle,	40	А				
Peak repetitive forward current per leg		I _{FRM}	Rated V _R , square wave, 20 kHz	40					
Maximum peak one cycle non-repetitive surge current per leg, see fig. 7		I =0.1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	1020				
		IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	265				
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.40 mH		20	mJ			
Repetitive avalanche current per leg			Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		3	А			

 Revision: 29-Apr-2020
 1
 Document Number: 96466

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ELECTRICAL SPECIFICATIONS PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		20 A	T, = 25 °C	0.59	N			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=25 0	0.78				
Maximum forward voltage drop	VFM \	20 A	T, = 125 °C	0.56	V			
		40 A	1j = 125 C	0.72				
Maximum instantaneous reverse current		T _J = 25 °C		1.75				
	I _{RM} ⁽¹⁾	T _J = 100 °C	Rated DC voltage	50	mA			
		T _J = 125 °C		110				
Threshold voltage	V _{F(TO)}			0.29	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		10.3	mΩ			
Maximum junction capacitance	CT	V _R = 5 V _{DC} (test signal ran	900	pF				
Typical series inductance	L _S	Measured from top of tern	7.5	nH				
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

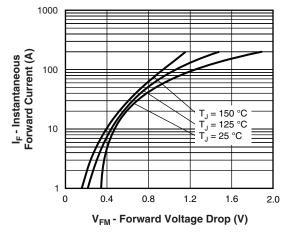
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 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-55 to 150	•	
Maximum storage temperature range	T _{Stg}	T _{Stg}		°C	
Maximum thermal resistance, junction to case per package	R _{thJC}	DC operation	1.4	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.7	0/11	
Approvimente weight			6	g	
Approximate weight			0.21	oz.	
Mounting torque			6 (5)	kgf · cm	
Mounting torque maximum			12 (10)	(lbf · in)	
Device marking		Case style TO-247AC 3L	MBR4	045WT	

VS-MBR4045WT-N3

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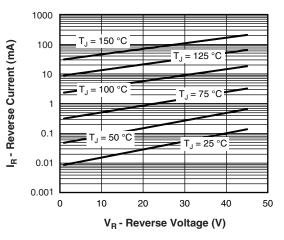


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

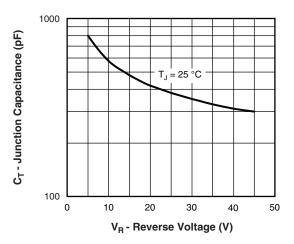


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

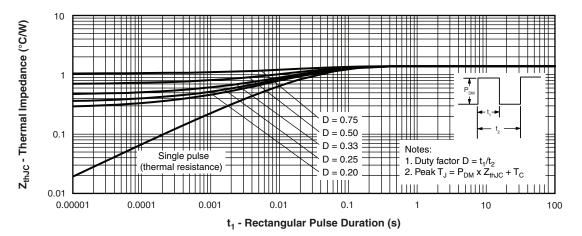
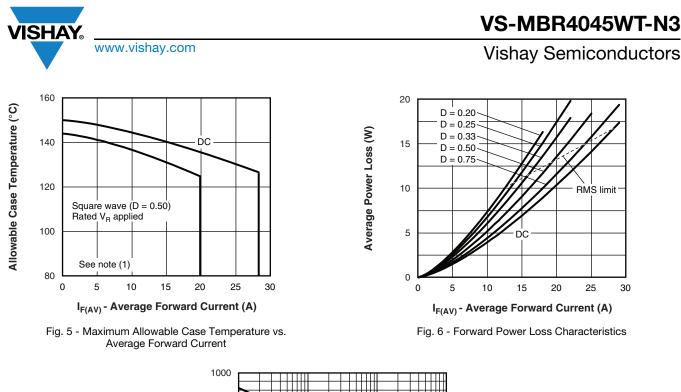


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



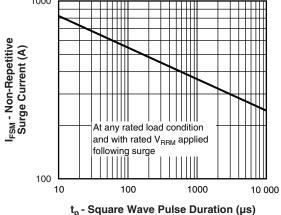


Fig. 7 - Maximum Non-Repetitive Surge Current

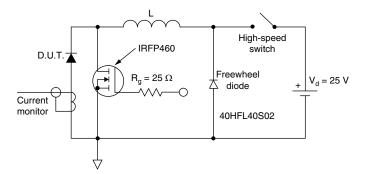


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽²⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{rated V}_{R} \end{array}$

Revision: 29-Apr-2020

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VS-MBR4045WT-N3

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ORDERING INFORMATION TABLE

Device code	VS-	MBR	40	45	ωт	-N3
		(2)	(3)	(4)	(5)	6
	\bigcirc		\bigcirc	4	\bigcirc	0
	<u> </u>	- Visł	nay Sem	niconduc	ctors pro	oduct
	2		•	BR serie ng (40 =		
	3 · 4 ·			ng (45 =	,	
	5		•	iguratior	,	
		Cer	iter tap	(dual) T	D-247	
	6			ntal digit		
		-N3	= halog	en-free,	RoHS-	complia

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBR4045WT-N3	25	500	Antistatic plastic tube					

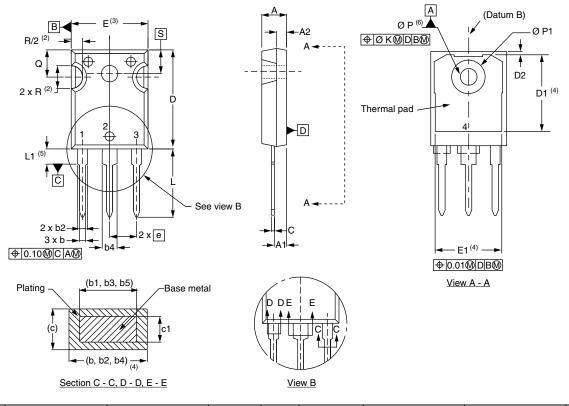
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96138					
Part marking information	www.vishay.com/doc?95007					
SPICE model	www.vishay.com/doc?95297					



Vishay Semiconductors

TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension Q

Revision: 20-Jun-17

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Revision: 01-Jan-2024